



TS922H

RAIL TO RAIL HIGH OUTPUT CURRENT DUAL OPERATIONAL AMPLIFIER

- RAIL TO RAIL INPUT AND OUTPUT
- LOW NOISE : **9nV/√(Hz)**
- LOW DISTORTION
- HIGH OUTPUT CURRENT : **80mA**
(able to drive 32Ω loads)
- HIGH SPEED : **4MHz, 1.3V/μs**
- OPERATING FROM **2.7V to 12V**
- LOW INPUT OFFSET VOLTAGE : **3.0mVmax**
- ESD INTERNAL PROTECTION : **2KV**
- LATCH-UP IMMUNITY

DESCRIPTION

The TS922 is a RAIL TO RAIL dual BiCMOS operational amplifier optimized and fully specified for 3V and 5V operation.

High output current allows low load impedances to be driven.

The TS922 exhibits a very low noise, low distortion, low offset and high output current capability making this device an excellent choice for high quality, low voltage or battery operated audio systems.

The device is stable for capacitive loads up to 500pF.

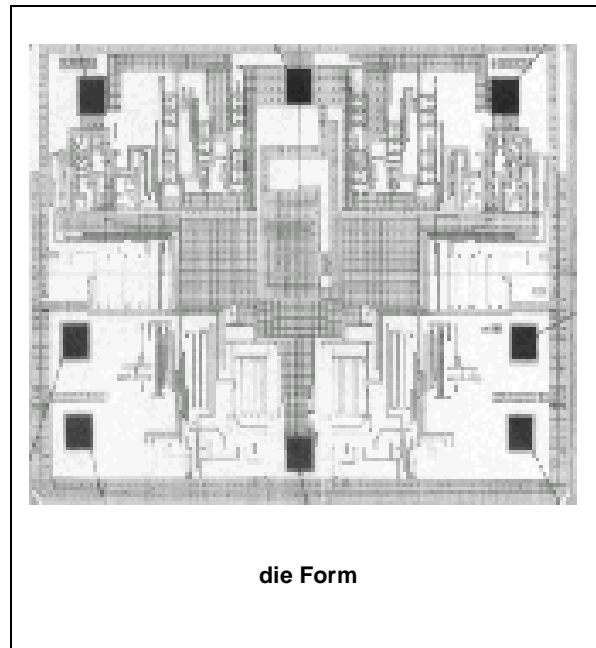
APPLICATIONS

- headphone amplifier
- piezoelectric speaker driver
- sound cards
- MPEG boards, multimedia systems, ...
- line driver, buffer
- cordless telephones and portable communication equipment
- instrumentation with low noise as key factor

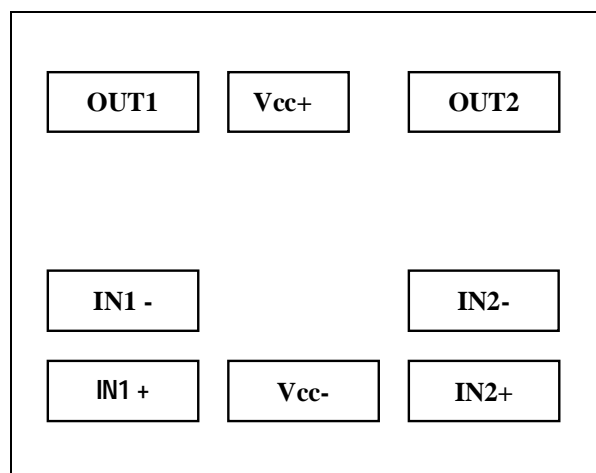
ORDER CODE

| Part Number | Temperature Range | Package | |
|--------------|-------------------|---------|--|
| | | Die | |
| JTS922H-DZD1 | -40°C, +150°C | • | |

Die = Wafer Form (not sawed)



PAD CONNECTION



ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|----------|------------------------------------------|------------------------|------|
| V_{CC} | Supply voltage ¹⁾ | 14 | V |
| V_{id} | Differential Input Voltage ²⁾ | ± 1 | V |
| V_i | Input Voltage ³⁾ | -0.3 to 14 | V |
| T_j | Maximum Junction Temperature | 155 | °C |
| | Output Short Circuit Duration | see note ⁴⁾ | S |

1. All voltages values, except differential voltage are with respect to network ground terminal.
2. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
3. The magnitude of input and output voltages must never exceed $V_{CC}^+ + 0.3V$.
4. Short-circuits can cause excessive heating. Destructive dissipation can result from simultaneous short-circuit on all amplifiers

OPERATING CONDITIONS

| Symbol | Parameter | Value | Unit |
|------------|--------------------------------------|--------------------------------------|------|
| V_{CC} | Supply voltage | 2.7 to 12 | V |
| T_{oper} | Operating Free Air Temperature Range | -40 to +150 | °C |
| V_{icm} | Common Mode Input Voltage Range | $V_{CC}^- - 0.2$ to $V_{CC}^+ + 0.2$ | V |

ELECTRICAL CHARACTERISTICS

$V_{CC^+} = 3V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
|-----------|--------------------------------------------------------------------------------------------------------------------|-------------|-----------------|-----------|------------------------|
| V_{io} | Input Offset Voltage $T_{min.} \leq T_{amb} \leq T_{max.}$ | | | 3 | mV |
| DV_{io} | Input Offset Voltage Drift | | 2 | | $\mu V/^{\circ}C$ |
| I_{io} | Input Offset Current $V_{OUT} = 1.5V$ | | 1 | 30 | nA |
| V_{oh} | High Level Output Voltage $R_L = 10k\Omega$ $R_L = 600\Omega$ $R_L = 32\Omega$ | 2.9 2.87 | 2.63 | | V |
| V_{oL} | Low Level Output Voltage $R_L = 10k\Omega$ $R_L = 600\Omega$ $R_L = 32\Omega$ | | 180 | 50 100 | mV |
| I_{ib} | Input Bias Current $V_{OUT} = 1.5V$ | | 15 | 100 | nA |
| AVD | Large Signal Voltage Gain ($V_{out} = 2V_{pk-pk}$) $R_L = 10k\Omega$ $R_L = 600\Omega$ $R_L = 32\Omega$ | | 200 35 16 | | V/mV |
| I_{cc} | Total Supply Current no load, $V_{out} = V_{cc}/2$ | | 2 | 3 | mA |
| GBP | Gain Bandwidth Product $R_L = 600\Omega$ | | 4 | | MHz |
| CMR | Common Mode Rejection Ratio | 60 | 80 | | dB |
| SVR | Supply Voltage Rejection Ratio $V_{cc} = 2.7$ to $3.3V$ | 60 | 85 | | dB |
| I_o | Output Short Circuit Current | 50 | 80 | | mA |
| SR | Slew Rate | 0.7 | 1.3 | | V/ μs |
| ϕ_m | Phase Margin at Unit Gain $R_L = 600\Omega$, $C_L = 100pF$ | | 68 | | Degrees |
| G_m | Gain Margin $R_L = 600\Omega$, $C_L = 100pF$ | | 12 | | dB |
| e_n | Equivalent Input Noise Voltage $f = 1kHz$ | | 9 | | $\frac{nV}{\sqrt{Hz}}$ |
| THD | Total Harmonic Distortion $V_{out} = 2V_{pk-pk}$, $F = 1kHz$, $A_v = 1$, $R_L = 600\Omega$ | | 0.005 | | % |
| C_s | Channel Separation | | 120 | | dB |

ELECTRICAL CHARACTERISTICS

$V_{CC^+} = 5V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
|-----------|--------------------------------------------------------------------------------------------------------------------|-------------|-----------------|-----------|------------------------|
| V_{io} | Input Offset Voltage $T_{min.} \leq T_{amb} \leq T_{max.}$ | | | 3 | mV |
| DV_{io} | Input Offset Voltage Drift | | 2 | | $\mu V/^{\circ}C$ |
| I_{io} | Input Offset Current $V_{OUT} = 1.5V$ | | 1 | 30 | nA |
| I_{ib} | Input Bias Current $V_{OUT} = 1.5V$ | | 15 | 100 | nA |
| I_{cc} | Total Supply Current no load, $V_{out} = V_{cc}/2$ | | 2 | 3 | mA |
| V_{oh} | High Level Output Voltage $R_L = 10k\Omega$ $R_L = 600\Omega$ $R_L = 32\Omega$ | 4.9 4.85 | 4.44 | | V |
| V_{oL} | Low Level Output Voltage $R_L = 10k\Omega$ $R_L = 600\Omega$ $R_L = 32\Omega$ | | 300 | 50 120 | mV |
| AVD | Large Signal Voltage Gain ($V_{out} = 2v_{pk-pk}$) $R_L = 10k\Omega$ $R_L = 600\Omega$ $R_L = 32\Omega$ | | 200 35 16 | | V/mV |
| GBP | Gain Bandwidth Product $R_L = 600\Omega$ | | 4 | | MHz |
| CMR | Common Mode Rejection Ratio | 60 | 80 | | dB |
| SVR | Supply Voltage Rejection Ratio $V_{cc} = 3V$ to $5V$ | 60 | 85 | | dB |
| I_o | Output Short Circuit Current | 50 | 80 | | mA |
| SR | Slew Rate | 0.7 | 1.3 | | V/ μs |
| ϕ_m | Phase Margin at Unit Gain $R_L = 600\Omega$, $C_L = 100pF$ | | 68 | | Degrees |
| G_m | Gain Margin $R_L = 600\Omega$, $C_L = 100pF$ | | 12 | | dB |
| e_n | Equivalent Input Noise Voltage $f = 1kHz$ | | 9 | | $\frac{nV}{\sqrt{Hz}}$ |
| THD | Total Harmonic Distortion $V_{out} = 2V_{pk-pk}$, $F = 1kHz$, $A_v = 1$, $R_L = 600\Omega$ | | 0.005 | | % |
| C_s | Channel Separation | | 120 | | dB |

SPICE MACROMODEL

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** Standard Linear Ics Macromodels, 1996.
** CONNECTIONS :
* 1 INVERTING INPUT
* 2 NON-INVERTING INPUT
* 3 OUTPUT
* 4 POSITIVE POWER SUPPLY
* 5 NEGATIVE POWER SUPPLY

.SUBCKT TS922 1 3 2 4 5 (analog)
*****
.MODEL MDTH D IS=1E-8 KF=2.664234E-16 CJO=10F
* INPUT STAGE
CIP 2 5 1.000000E-12
CIN 1 5 1.000000E-12
EIP 10 5 2 5 1
EIN 16 5 1 5 1
RIP 10 11 8.125000E+00
RIN 15 16 8.125000E+00
RIS 11 15 2.238465E+02
DIP 11 12 MDTH 400E-12
DIN 15 14 MDTH 400E-12
VOFP 12 13 DC 153.5u
VOFN 13 14 DC 0
IPOL 13 5 3.200000E-05
CPS 11 15 1e-9
DINN 17 13 MDTH 400E-12
VIN 17 5 -0.100000e+00
DINR 15 18 MDTH 400E-12
VIP 4 18 0.400000E+00
FCP 4 5 VOFP 1.865000E+02
FCN 5 4 VOFN 1.865000E+02
FIBP 2 5 VOFP 6.250000E-03
FIBN 5 1 VOFN 6.250000E-03
* GM1 STAGE *****
FGM1P 119 5 VOFP 1.1
FGM1N 119 5 VOFN 1.1
RAP 119 4 2.6E+06
RAN 119 5 2.6E+06
* GM2 STAGE *****
G2P 19 5 119 5 1.92E-02

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G2N 19 5 119 4 1.92E-02
R2P 19 4 1E+07
R2N 19 5 1E+07
*****
VINT1 500 0 5
GCONVP 500 501 119 4 19.38 !envoi ds VP,
I(VP)=(V119-V4)/2/Ut VP 501 0 0
GCONVN 500 502 119 5 19.38 !envoi ds VN,
I(VN)=(V119-V5)/2/Ut VN 502 0 0
***** orientation isink isource *****
VINT2 503 0 5
FCOPY 503 504 VOUT 1
DCOPYP 504 505 MDTH 400E-9
VCOPYP 505 0 0
DCOPYN 506 504 MDTH 400E-9
VCOPYN 0 506 0
*****
F2PP 19 5 poly(2) VCOPYP VP 0 0 0 0 0.5 !multiplie
I(vout)*I(VP)=Iout*(V119-V4)/2/Ut
F2PN 19 5 poly(2) VCOPYP VN 0 0 0 0 0.5 !multiplie
I(vout)*I(VN)=Iout*(V119-V5)/2/Ut
F2NP 19 5 poly(2) VCOPYN VP 0 0 0 0 1.75 !multiplie
I(vout)*I(VP)=Iout*(V119-V4)/2/Ut
F2NN 19 5 poly(2) VCOPYN VN 0 0 0 0 1.75 !multiplie
I(vout)*I(VN)=Iout*(V119-V5)/2/Ut
* COMPENSATION *****
CC 19 119 25p
* OUTPUT*****
DOPM 19 22 MDTH 400E-12
DONM 21 19 MDTH 400E-12
HOPM 22 28 VOUT 6.250000E+02
VIPM 28 4 5.000000E+01
HONM 21 27 VOUT 6.250000E+02
VINM 5 27 5.000000E+01
VOUT 3 23 0
ROUT 23 19 6
COUT 3 5 1.300000E-10
DOP 19 25 MDTH 400E-12
VOP 4 25 1.052
DON 24 19 MDTH 400E-12
VON 24 5 1.052
.ENDS

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ELECTRICAL CHARACTERISTICS

V_{CC}⁺ = 3V, V_{CC}⁻ = 0V, R_L, C_L connected to V_{CC/2}, T_{amb} = 25°C (unless otherwise specified)

| Symbol | Conditions | Value | Unit |
|---------------------|-----------------------------------------------|-------------|---------|
| V _{io} | | 0 | mV |
| A _{vd} | R _L = 10kΩ | 200 | V/mV |
| I _{CC} | No load, per operator | 1.2 | mA |
| V _{icm} | | -0.2 to 3.2 | V |
| V _{OH} | R _L = 10kΩ | 2.95 | V |
| V _{OL} | R _L = 10kΩ | 25 | mV |
| I _{sink} | V _O = 3V | 80 | mA |
| I _{source} | V _O = 0V | 80 | mA |
| GBP | R _L = 600kΩ | 4 | MHz |
| SR | R _L = 10kΩ, C _L = 100pF | 1.3 | V/μs |
| φ _m | R _L = 600kΩ | 68 | Degrees |

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